# Control Design for Optimizing Efficiency in Inductive Power Transfer Systems

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Abstract—Inductive power transfer (IPT) converters are resonant converters that attain optimal energy efficiencies for a certain load range. To achieve maximum efficiency, it is common to cascade the IPT converter with front-side and load-side dc/dc converters. The two dc/dc converters are normally controlled cooperatively for the requirements of output regulation and maximum efficiency tracking using a control technique based on perturbation and observation, which is inevitably slow in response. In this paper, a decoupled control technique is developed. The load-side dc/dc converter is solely responsible for output regulation, while the front-side converter is responsible for impedance-matching of the IPT converter by controlling its input-to-output voltage ratio. The controls are linear and therefore fast. DC and small-signal transfer functions are derived for designing the control parameters. The performances of fast regulation and high efficiency of the IPT converter system are verified using a prototype system.

*Index Terms*—Control for maximum efficiency, inductive power transfer (IPT), wireless power transfer.

## I. INTRODUCTION

ESIGN and optimization of inductive power transfer (IPT) systems have been widely studied. One of the main objectives is to achieve high efficiency. The optimization involves the choice of appropriate structure of magnetic couplers [1] and their interoperability [2]. It is well known that a higher coupling coefficient and higher coil quality factors of the pair of windings of the magnetic coupler would increase the system efficiency [3], [4]. Optimization approaches for these two parameters to achieve high efficiency have been proposed [5], [6]. Meanwhile, since the system efficiency is not monotonically varying with the load, optimum loads that achieve maximum efficiency of the system are also studied [7]-[9]. Moreover, various design aspects to achieve maximum efficiency for different converter input-output transfer functions using series and parallel compensations have been studied [10], [11]. Previous studies show that given a coupling coefficient and coil quality factors, an IPT converter should be designed to operate at

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some fixed operating frequencies with load-independent transfer characteristic and slight modulation for soft switching when a simple half-bridge or full-bridge inverter circuit is used, and to operate within a restricted load range in order to achieve maximum efficiency [10]–[13]. Among the four basic types of compensation, the widely used *series–series* compensated IPT (SSIPT) converter is the most power efficient IPT converter when it is operating with load-independent output current [7]–[13]. However, in some practical applications, the design may not meet the required wide variations of the coupling coefficient, the load resistance, and the load power. Thus, once an IPT converter has been designed at a particular coupling coefficient and a particular load, the efficiency of the IPT system cannot always be maintained near its maximum point.

To improve the system efficiency under variation of the load, a load-side dc/dc converter is connected between the load and the secondary of an SSIPT converter to adaptively control the equivalent load observed by the SSIPT converter, thus maintaining a maximum efficiency of the front-end power amplifier driver [14], [15]. To achieve output regulation, source modulation is needed. The modulation can be provided by either a pulse width modulated inverter, a front-side dc/dc converter which amplitude modulates the inverter circuit, or a power amplifier. The inverter circuit is mostly implemented by either a half-bridge or full-bridge circuit, which provides the highest efficiency but suffers from shallow modulation due to the need for maintaining soft switching [9]-[11]. The depth of modulation can be greatly improved when the inverter is amplitude modulated by a front-end dc/dc converter. The combined circuit incurs a penalty of additional loss due to the extra power stage. The power amplifier can be considered as a circuit consisting of a front-side dc/dc converter, amplitude modulating an inverter circuit, with an output filter. The study by Li et al. [16] shows that a system consisting of an SSIPT converter with front-side and load-side dc/dc converters (the system is denoted as F-SSIPT-L) can achieve better overall system efficiency compared to a system consisting of the same SSIPT converter and a load-side dc/dc converter utilizing the modulation of the internal inverter (such a system is denoted as M-SSIPT-L) with frequency modulation. A maximum efficiency tracking (MET) algorithm has been proposed by Li et al. [16], where the secondary dc/dc converter regulates the output voltage while the front-side dc/dc converter maximizes the system efficiency. Another MET algorithm has also been studied using the F-SSIPT-L system where the front-side dc/dc converter controls the input current of the SSIPT converter for better handling of small coupling

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For simplicity, the SSIPT converter is normally designed to operate at the aligned resonant frequency, i.e.,  $\omega = \omega_P = \omega_S$ , where  $\omega_P = \frac{1}{\sqrt{L_P C_P}}$  and  $\omega_S = \frac{1}{\sqrt{L_S C_S}}$  [9], [18]. As a result,  $\eta$  in (1) is maximized at a particular load  $R_{L,opt}$ , which can be calculated by solving  $\frac{\partial \eta}{\partial R_I} = 0$ , i.e.,

$$R_{L,\text{opt}} = R_S \sqrt{1 + \frac{\omega^2 M^2}{R_P R_S}}$$
(3)

$$\approx \omega M \sqrt{\frac{R_S}{R_P}} \text{ for } \frac{\omega^2 M^2}{R_P R_S} \gg 1.$$
 (4)

The magnitude of the transconductance |G| at this operating frequency is given by

$$G| = \left|\frac{i_o}{v_i}\right| = \frac{\omega M}{R_P(R_S + R_L) + \omega^2 M^2} \tag{5}$$

for  $\frac{\omega^2 M^2}{R_P R_S} \gg 1$  and  $\frac{\omega^2 M^2}{R_P R_L} \gg 1$ . The magnitude of the voltage transfer ratio |H| at maximum efficiency is thus given by

$$|H| = \left|\frac{v_o}{v_i}\right| = |G| R_{L,\text{opt}} \approx \sqrt{\frac{R_S}{R_P}}.$$
 (6)

From (6), it is possible to maintain a high IPT converter efficiency by controlling the converter voltage ratio at  $|H| = \sqrt{\frac{R_s}{R_P}}$ against variation of the load.

# III. SSIPT CONVERTER VOLTAGE RATIO CONTROL

A general three-stage IPT system is shown in Fig. 2 [16]–[18]. The IPT system includes a front-side dc/dc converter, an SSIPT converter, and a load-side dc/dc converter. The operating frequency of the inverter is fixed at the resonant frequency to achieve maximum efficiency. The control functions of the three-stage system provide:

- 1) regulation to the output voltage or current; and
- 2) control for maximum efficiency of the SSIPT converter.

Three control schemes with control functions  $V_{\rm err}(m_1)$ ,  $\eta(m_1)$  and  $P_{\mathrm{IN}}(m_1)$  are shown in Fig. 2 and compared in Table I, where  $m_1$  is a modulation index of  $V_{IN}$ . The following advantages of our proposed linear control method can be readily observed.

- 1) The control function versus modulated index  $m_1$ (e.g., duty cycle of the front-side converter) is monotonic with a well-defined control reference  $V_{\rm err} = 0$  to minimize error voltage  $V_{\rm err} = V_1 - \sqrt{\frac{R_P}{R_S}}V_2$ , i.e., to achieve the desired |H| in (6). With a proper design, a simple linear proportional integral (PI) controller can be implemented in either analog or digital form. This results in a faster response.
- 2) The sampled voltages can be used for the linear PI controller without further processing. This results in a faster and more accurate response. Moreover, no current sensor is required, and the system cost is lower.

Fig. 1. IPT converter model.

coefficient and light load [17]. Furthermore, an MET algorithm has been applied to the inverter to minimize the input power of an M-SSIPT-L system where the load-side dc/dc converter solely regulates the output [18]. The benefit is that no wireless data feedback is needed from the secondary to the primary of the magnetic coupler. The MET control schemes studied so far are based on perturbation and observation (P&O) of the system power or the system efficiency [15]–[18]. It is well known that P&O-based control schemes are slow due to the uncertainties of perturbation speed and amplitude. Moreover, such control schemes are based on real-time processing of both voltage and current for obtaining information of power or efficiency, resulting in high error of the processed information and necessitating the use of cost-ineffective current sensor(s). In this paper, a simple and fast voltage control scheme for achieving maximum efficiency of the SSIPT converter is proposed for applications requiring fast regulation of load powers, such as charging of electric vehicles [29]–[31] and biomedical implants [32], [33].

# II. MAXIMUM IPT CONVERTER EFFICIENCY AND VOLTAGE RATIO

Fig. 1 shows an equivalent circuit of a commonly used SSIPT converter model, where the magnetic coupler has selfinductances  $L_P$  and  $L_S$ , and mutual inductance M. The magnetic coupler is compensated by external series compensated capacitors  $C_P$  and  $C_S$ . Subscripts P and S indicate parameters on the primary and secondary sides, respectively, of the magnetic coupler. The circuit is simplified as being driven by an approximate equivalent ac voltage source  $v_i$  at a fundamental angular frequency  $\omega$  modulated by the inverter. The output is usually rectified to drive a dc load with  $R_L$  being the ac equivalent resistance. Losses are modeled aggregately using equivalent series resistors  $R_P$  and  $R_S$  [10]. Resistor  $R_P$  includes losses from the primary windings and the inverter circuit, while resistor  $R_S$  includes losses from the secondary windings and the rectifier circuit.

This SSIPT model has been studied in [9]–[11] with converter efficiency  $\eta$  and transconductance G given as

$$\eta(\omega, R_L) = \frac{\omega^2 M^2 R_L}{|Z_S + R_L|^2 R_P + \omega^2 M^2 (R_S + R_L)}, \text{ and} \quad (1)$$

$$G(\omega) = \frac{i_o}{v_i} = \frac{j\omega M}{Z_P(Z_S + R_L) + \omega^2 M^2}$$
(2)





Fig. 2. SSIPT converter cascaded with a front-side converter and a load-side converter.



TABLE I COMPARISON OF DIFFERENT CONTROL SCHEMES

The steady-state operation of the converter system is studied in this section. Small-signal analysis will be conducted in Section IV. The load-side converter regulates the output voltage or current so that the load appears as a power load  $P_O$  at the output of the SSIPT converter. Power balance requires that  $P_O = V_2 I_2$ . Substituting (5) and applying a scaling factor between square and sinusoidal magnitudes, we have  $\frac{1}{\omega M} = \begin{vmatrix} i_0 \\ v_i \end{vmatrix} = \frac{\frac{\pi}{2} I_2}{\frac{1}{2} V_1}$ , which gives

$$P_O = V_2 \frac{8}{\pi^2 \omega M} V_1. \tag{7}$$

To achieve (6), it is equivalent to minimize  $|V_{err}|$  given by

$$V_{\rm err} = V_1 - \sqrt{\frac{R_P}{R_S}} V_2 = V_1 - \sqrt{\frac{R_P}{R_S}} \frac{P_O \pi^2 \omega M}{8} \frac{1}{V_1}.$$
 (8)

When using a front-side pulse width modulation (PWM) converter,  $V_1$  is the modulated output of  $V_{\rm IN}$  from modulation index  $m_1 = \frac{V_1}{V_{\rm IN}}$ . Monotonic curves for the control function  $V_{\rm err}$  of (8) are shown in Table I for various values of coupling coefficient  $k = \frac{M}{\sqrt{L_P L_S}}$ . A linear PI controller can be used for its simple structure, better robustness, and high reliability. The design will be presented in Section IV.

#### **IV. CONTROLLER DESIGN**

Linear PI controllers will be designed to optimize the efficiency of the SSIPT converter system. Fig. 3 shows a proposed schematic of control for the system. For the SSIPT converter, an H-bridge inverter is used to generate an ac voltage at the resonant frequency. Thus, the SSIPT converter behaves as a transconductance converter [11]. The current output is cascaded with a buck-boost converter, which is regulated with a standalone PI controller to generate a constant voltage output  $V_{\rm OUT}$ . The front-side converter is a buck converter whose output voltage  $V_1$  drives the SSIPT converter. Voltages  $V_1$  and  $V_2$  of the SSIPT converter are sampled. No current sensor is needed here. Voltage  $V_2$  after being scaled by a factor of  $\sqrt{\frac{R_P}{R_S}}$  is transmitted wirelessly from the secondary to the primary of the magnetic coupler and connected to the input of the PI controller of the buck converter. The voltage error  $V_{\rm err}$  is nulled by the PI controller of the buck converter to achieve maximum efficiency of the SSIPT converter.

At the optimal efficiency point, steady-state parameters of the converters are calculated using  $R_{\rm eq} = \frac{\pi^2}{8} \omega M \sqrt{\frac{R_S}{R_P}}$ ,  $R_{\rm buck} = \frac{\pi^2}{8} \omega M \sqrt{\frac{R_P}{R_S}}$ ,  $V_2 = V_{\rm OUT} \sqrt{\frac{R_{\rm eq}}{R}}$ , and  $V_1 = V_{\rm OUT} \sqrt{\frac{R_{\rm buck}}{R}}$ . For



Fig. 3. Schematic of the system.

simplicity, the front-side and load-side converters are assumed lossless.

## A. SSIPT Model

The small-signal transfer function of the SSIPT converter can be derived and calculated using the *generalized averaging technique* given in [19] and [20] for ordinary PWM and resonant power converters. Later, the same technique has been rephrased as *dynamic-phasor model* and applied for single-phase induction machines [21], microgrid systems [27], and extended for the predictive control of power converters [28]. Since the application of the generalized averaging technique or the dynamic-phasor model may not be obvious for IPT converters, the procedure is highlighted as follows. A sinusoidal signal x(t) with timevarying magnitude X and phase angle  $\theta$  can be written as

$$x(t) = X\sin\left(\omega t + \theta\right) \tag{9}$$

$$= X \left[ \cos \theta \sin \omega t + \sin \theta \cos \omega t \right]$$
(10)

$$= X_d \sin \omega t + X_q \cos \omega t \tag{11}$$

$$=\Im\left((X_d+jX_q)e^{j\omega t}\right),\tag{12}$$

where  $X_d = X \cos \theta$  and  $X_q = X \sin \theta$  are the direct and quadrature components of x(t), respectively. The time functions of the slow time-varying properties of X,  $\theta$ ,  $X_d$ , and  $X_q$ are omitted for brevity. It can be readily shown that

$$\frac{dx(t)}{dt} = \Im\left\{\left[\left(\frac{dX_d}{dt} - \omega X_q\right) + j\left(\frac{dX_q}{dt} + \omega X_d\right)\right]e^{j\omega t}\right\}.$$
(13)

For a pure capacitor C having current  $i_C(t)$  and voltage  $v_C(t)$ , and a pure inductor L having current  $i_L(t)$  and voltage  $v_L(t)$ , the following basic relationships hold:

$$i_C(t) = C \frac{dv_C(t)}{dt}, \text{ and}$$
(14)

$$w_L(t) = L \frac{di_L(t)}{dt}.$$
(15)

Substituting (12) and (13) into (14) and (15) and simplifying, we have

$$I_{C,d} + jI_{C,q} = C\left(\frac{dV_{C,d}}{dt} - \omega V_{C,q}\right)$$
$$+ j\left(\frac{dV_{C,q}}{dt} + \omega V_{C,d}\right), \text{ and } (16)$$
$$V_{L,d} + jV_{L,q} = L\left(\frac{dI_{L,d}}{dt} - \omega I_{L,q}\right)$$

$$+ jV_{L,q} = L\left(\frac{dI_{L,d}}{dt} - \omega I_{L,q}\right)$$
$$+ j\left(\frac{dI_{L,q}}{dt} + \omega I_{L,d}\right).$$
(17)

We can write x(t) as a complex vector given as  $X = X_d + jX_q$ . Hence, (16) and (17) can be simplified at steady state to become

$$\dot{I}_C = I_{C,d} + jI_{C,q} = j\omega \dot{V}_C$$
, and (18)

$$\dot{V}_L = V_{L,d} + jV_{L,q} = j\omega\dot{I}_L \tag{19}$$

which is commonly used in complex vector analysis. Obviously, (16) and (17) are vector transformations of (14) and (15). We can write (16) and (17) in matrix forms as

$$\mathbf{I}_{C} = C\left(\mathbb{I}_{\omega} + \frac{d}{dt}\right) \mathbf{V}_{C}, \text{ and}$$
(20)

$$\mathbf{V}_L = L\left(\mathbb{I}_\omega + \frac{d}{dt}\right)\mathbf{I}_L \tag{21}$$

where  $\mathbf{X}_{Y} = [X_{Y,d}, X_{Y,q}]^{T}$  is a column vector and

$$\mathbb{I}_{\omega} = \begin{pmatrix} 0 & -\omega \\ \omega & 0 \end{pmatrix} \tag{22}$$

is a  $2 \times 2$  matrix.

The SSIPT system shown in Fig. 1 is governed by a state-space equation given as

$$\frac{d}{dt}X = AX + BV \tag{23}$$

where

$$X = \begin{bmatrix} v_P(t) & v_S(t) & i_P(t) & i_S(t) \end{bmatrix}^T$$
(24)

$$V = \begin{bmatrix} v_i(t) & v_o(t) \end{bmatrix}^T$$
(25)

$$A = \begin{bmatrix} 0 & 0 & \frac{1}{C_{P}} & 0 \\ 0 & 0 & 0 & \frac{1}{C_{S}} \\ -\alpha_{P} & \beta & -\alpha_{P}R_{P} & \beta R_{S} \\ \beta & -\alpha_{S} & \beta R_{P} & -\alpha_{S}R_{S} \end{bmatrix}$$
(26)  
$$B = \begin{bmatrix} 0 & 0 & \alpha_{P} & -\beta \\ 0 & 0 & -\beta & \alpha_{S} \end{bmatrix}^{T}$$
(27)

$$\alpha_P = \frac{1}{L_P(1-k^2)} \tag{28}$$

$$\alpha_S = \frac{1}{L_S(1-k^2)} \tag{29}$$

$$\beta = \frac{k}{(1-k^2)\sqrt{L_P L_S}}.$$
(30)

Here,  $v_P(t)$  is the voltage of  $C_P$ ,  $v_S(t)$  is the voltage of  $C_S$ ,  $i_P(t)$  is the current of  $L_P$ , and  $i_S(t)$  is the current of  $L_S$ . The SSIPT system has input  $v_i(t)$  and output  $v_o(t)$  powering load  $R_L$ . All state variables are sinusoidal.

Equation (23) can be readily vector transformed using (20) and (21) to obtain

$$\frac{d}{dt}\mathbf{X} = \mathbf{A}\mathbf{X} + \mathbf{B}\mathbf{V}$$
(31)

where

$$\mathbf{X} = \begin{bmatrix} \mathbf{V}_{\mathbf{P}} & \mathbf{V}_{S} & \mathbf{I}_{P} & \mathbf{I}_{S} \end{bmatrix}^{T}$$
(32)

$$\mathbf{V} = \begin{bmatrix} \mathbf{V}_{\mathbf{I}} & \mathbf{V}_{O} \end{bmatrix}^{T}$$
(33)

$$\mathbf{A} = \begin{bmatrix} -\mathbb{I}_{\omega} & 0 & \frac{1}{C_{P}}\mathbb{I}_{2} & 0\\ 0 & -\mathbb{I}_{\omega} & 0 & \frac{1}{C_{S}}\mathbb{I}_{2}\\ -\alpha_{P}\mathbb{I}_{2} & \beta\mathbb{I}_{2} & -\alpha_{P}R_{P}\mathbb{I}_{2} - \mathbb{I}_{\omega} & \beta R_{S}\mathbb{I}_{2}\\ \beta\mathbb{I}_{2} & -\alpha_{S}\mathbb{I}_{2} & \beta R_{P}\mathbb{I}_{2} & -\alpha_{S}R_{S}\mathbb{I}_{2} - \mathbb{I}_{\omega} \end{bmatrix}$$
(34)

$$\mathbf{B} = \begin{bmatrix} 0 & 0 & \alpha_P \mathbb{I}_2 & -\beta \mathbb{I}_2 \\ 0 & 0 & -\beta \mathbb{I}_2 & \alpha_S \mathbb{I}_2 \end{bmatrix}^T.$$
(35)

 $\mathbb{I}_2$  is the two-dimensional identity matrix and variable  $\mathbf{X}_Y = (X_{Yr}, X_{Yi})^T$ .

A converter is cascaded with the SSIPT instead of a resistor. Assumed that the converter is well controlled to maintain a constant voltage or current output, it can be considered as a constant power load [22]. The extended describing function of  $\mathbf{V}_O$  is given by

$$V_{O,d} = -2P_O \frac{I_{S,d}}{I_{S,d}^2 + I_{S,q}^2}$$
(36)

$$V_{O,q} = -2P_O \frac{I_{S,q}}{I_{S,d}^2 + I_{S,q}^2}$$
(37)

where  $P_O$  is the output power of the SSIPT. With (31), (36), and (37), the small-signal model of (31) can be derived as

$$\begin{cases} \frac{d}{dt}\hat{\mathbf{X}} = \hat{\mathbf{A}}\hat{\mathbf{X}} + \hat{\mathbf{B}}\hat{\mathbf{V}}_{I} \\ \hat{\mathbf{I}}_{O} = \hat{\mathbf{C}}\hat{\mathbf{X}} \end{cases}$$
(38)

where

$$\hat{\mathbf{X}} = \begin{bmatrix} \mathbf{V}_{\mathbf{P}} & \mathbf{V}_{S} & \mathbf{I}_{P} & \mathbf{I}_{S} \end{bmatrix}^{T}$$
(39)

$$\hat{\mathbf{V}}_{I} = \begin{bmatrix} \mathbf{V}_{\mathbf{I},\mathbf{d}} & \mathbf{V}_{I,q} \end{bmatrix}^{T}$$
(40)

$$\hat{\mathbf{I}}_{O} = \begin{bmatrix} \mathbf{I}_{\mathbf{O},\mathbf{d}} & \mathbf{I}_{O,q} \end{bmatrix}^{T}$$
(41)

 $\hat{\mathbf{A}} =$ 

$$\begin{bmatrix} -\mathbb{I}_{\omega} & 0 & \frac{1}{C_{P}}\mathbb{I}_{2} & 0 \\ 0 & -\mathbb{I}_{\omega} & 0 & \frac{1}{C_{S}}\mathbb{I}_{2} \\ -\alpha_{P}\mathbb{I}_{2} & \beta\mathbb{I}_{2} & -\alpha_{P}R_{P}\mathbb{I}_{2} - \mathbb{I}_{\omega} & \beta(R_{S}\mathbb{I}_{2} + \mathbb{I}_{\delta}) \\ \beta\mathbb{I}_{2} & -\alpha_{S}\mathbb{I}_{2} & \beta R_{P}\mathbb{I}_{2} & -\alpha_{S}(R_{S}\mathbb{I}_{2} + \mathbb{I}_{\delta}) - \mathbb{I}_{\omega} \end{bmatrix}$$
(42)

$$\hat{\mathbf{B}} = \begin{bmatrix} 0 & 0 & \alpha_P \mathbb{I}_2 & -\beta \mathbb{I}_2 \end{bmatrix}^T$$
(43)

$$\hat{\mathbf{C}} = \begin{bmatrix} 0 & 0 & 0 & -\mathbb{I}_{\omega} \end{bmatrix}$$
(44)

$$\mathbb{I}_{\delta} = \begin{pmatrix} P & -P \\ P & -P \end{pmatrix} \text{ and }$$
(45)

$$P = 2P_O \frac{-i_{S,d}^2 + i_{S,q}^2}{\left(i_{S,d}^2 + i_{S,q}^2\right)^2}.$$
(46)

The frequency response of the transconductance of the SSIPT converter is plotted using MATLAB with details shown in Fig. 4. We observe that within a bandwidth of one-hundredth of the fundamental frequency, the simulated transconductance can be approximated as an ideal transconductance  $\frac{1}{\omega M}$ , which is load independent.

#### B. Voltage Error Control Loop

We define  $\hat{x}_y$  as the small-signal variable of  $X_y$ . Since the designed bandwidth of the control will be far lower than one-hundredth of the fundamental frequency, the SSIPT converter in Fig. 3 will be considered as a constant transconductance, given by

$$G_I = \frac{\hat{i}_2}{\hat{v}_1} = \frac{8}{\pi^2} \frac{1}{\omega M}.$$
 (47)

General wireless communication protocols, such as 2.4G, are fast enough to transmit the output voltage  $V_2$  of the SSIPT



Fig. 4. Simulated frequency response of transconductance of the SSIPT model. Parameters used in simulation are:  $L_P = L_S = 30 \ \mu\text{H}$ ,  $C_P = C_S = 21.11 \text{ nF}$ ,  $R_P = R_S = 0.5 \ \Omega$ ,  $\frac{\omega}{2\pi} = 200 \text{ kHz}$ ,  $v_i = 30 \text{ V}$ , and  $P_O = 60 \text{ W}$ .



Fig. 5. Block diagram of the voltage control loop of the cascaded buck-SSIPT converter system.

converter, and the time delay is not considered here [3]. The load-side buck-boost converter is assumed to be ideally controlled as a constant power load, its small-signal input impedance is considered as a negative resistance  $-R_{\rm eq}$  in this small-signal model [22]. Voltage  $\hat{v}_2$  is, thus, given as

$$\hat{v}_2 = \hat{v}_1 G_I(-R_{\rm eq}) = -\hat{v}_1 \sqrt{\frac{R_S}{R_P}}.$$
 (48)

From (6) and the bandwidth considered, the voltage error transfer function of the SSIPT converter is assumed as

$$G_{\text{verr}} = \frac{\hat{v}_1 - \hat{v}_2}{\hat{v}_1} = 1 + \sqrt{\frac{R_S}{R_P}}.$$
 (49)

The input voltage  $\hat{v}_1$  of the SSIPT converter is controlled by the front-side buck converter shown in Fig. 3, the control-tooutput transfer function of the buck converter is given by [23]

$$G_{\rm vd1} = \frac{\hat{v}_1}{\hat{d}_1} = \frac{V_{\rm IN}}{L_a C_a s^2 + \frac{L_a}{R_{\rm buck}} s + 1}.$$
 (50)

The control loop of the system is shown in Fig. 5. The transfer function of the input duty cycle  $\hat{d}_1$  to the voltage error  $\hat{v}_{\text{err}}$  is given by  $G_{\text{vd}1}G_{\text{verr}}$ , of which the Bode diagram is shown in Fig. 6(a). For this system, the design of the compensator  $G_{C1}$ is similar to that of a buck converter [24]. Thus, a simple PI controller  $G_{C1}$  can be chosen as

$$G_{C1} = \frac{K_P s + K_I}{s}.$$
(51)



Fig. 6. Small-signal characteristics of the buck-SSIPT converter. Simulation parameters of the SSIPT converter are  $L_P = L_S = 30 \ \mu\text{H}$ ,  $C_P = C_S = 21.11 \text{ nF}$ , and  $\frac{\omega_P}{2\pi} = \frac{\omega_S}{2\pi} = 200 \text{ kHz}$ . Parameters of the buck converter are  $L_a = 1.2 \text{ mH}$ ,  $C_a = 760 \ \mu\text{F}$ ,  $V_{\text{IN}} = 50 \text{ V}$ ,  $V_O = 30 \text{ V}$ , and  $R = 20 \Omega$ . (a) Frequency response of  $\hat{v}_{\text{err}}$  versus  $\hat{d}_1$ . (b) Locations of pole (marked with "x") and zero (marked with "o") of the buck-SSIPT converter with  $K_P = 0.01$ ,  $K_I = 0.5$ , when k increases from 0.1 to 0.3 as indicated by the arrow direction.

#### C. Stability Analysis

The open-loop transfer function T of the front-side buck converter cascaded with the SSIPT converter (buck-SSIPT converter) is given by

$$T = G_{C1}G_{\rm vd1}G_{\rm verr}.$$
(52)

By substituting (49), (50), and (51) into (52) and putting 1 + T = 0, a third-order characteristic equation of the buck-SSIPT converter is obtained as

$$a_3s^3 + a_2s^2 + a_1s + a_0 = 0 (53)$$

where  $a_3 = L_a C_a$ ,  $a_2 = \frac{L_a}{R_{\text{buck}}}$ ,  $a_1 = (1 + \sqrt{\frac{R_S}{R_P}})K_P V_{\text{IN}} + 1$ , and  $a_0 = (1 + \sqrt{\frac{R_S}{R_P}})K_I V_{\text{IN}}$ .

The load R and the coupling coefficient k usually vary within some ranges during operation. For stable control,  $K_P$  and  $K_I$ should be designed to ensure system stability for the whole operating range. From the characteristic equation, R does not



Fig. 7. Experiment setup of the system and enlarged image of the loosely coupled transformer.

contribute to the design of  $K_P$  and  $K_I$ . An example design of the controller shown in Fig. 6(b) illustrates that all roots locate on the left-half plane. Therefore, the stability of the system is ensured for k varying from 0.1 to 0.3.

#### V. EXPERIMENTAL VERIFICATION

An experimental prototype as shown in Fig. 7 is built to verify the linear control scheme and a version of P&O control scheme [18] is also implemented for comparison. The parameters of the schematic shown in Fig. 3 are given in Table II.

## A. Design of Control Parameters

When the magnetic coupler is designed without a magnetic core, the variation of the air gap distance has little effect on the self-inductances. Thus, the resonant frequency can be considered as constant and the operating frequency of the inverter can be fixed. However, when the magnetic coupler is designed with a magnetic core to improve the coupling coefficient, the variation of the air gap distance will affect the self-inductances significantly [25]. Therefore, the operating frequency of the inverter should be dynamically adjusted to match the resonant frequency by using additional control, such as the self-oscillating control given in [26]. For the prototype studied in this paper, since the magnetic coupler is designed without a magnetic core, the variation of the air gap distance has little effect on the selfinductances, as shown in Table II, and no additional control for frequency adaptation is applied. The input voltage  $V_{\rm IN}$  of this prototype is fixed at 50 V. The output voltage  $V_{\rm OUT}$  is maintained at 30 V. A PI controller with  $K_P = 0.01$  and  $K_I = 0.5$ is designed for voltage control.

The SSIPT converter is designed to operate at zero inputphase angle. Apart from the winding loss, additional loss to be incorporated into  $R_P$  from the inverter includes conduction loss from  $R_{on}$  and turn-on loss  $P_{switch-on}$  of the MOSFET switches. Additional loss to be incorporated into  $R_S$  includes loss due to the rectifier forward voltage  $V_F$ . Therefore,  $R_P$  and  $R_S$  in (6) are approximated as  $R_P \approx R_{P,w} + 2R_{on} + \frac{16P_{switch-on}}{\pi^2 I_1^2}$  and  $R_S \approx R_{S,w} + \frac{16V_F}{\pi^2 I_2}$ , where  $R_{P,w}$  and  $R_{S,w}$  are the primary and secondary winding resistances, respectively, of the magnetic coupler.

The efficiency of the SSIPT converter is measured by a Yokogawa PX8000 Precision Power Scope. The buck-boost converter is closed-loop controlled and the buck converter is also closed-loop controlled with different control references. The efficiency curves of the SSIPT converter versus output power for different values of the voltage ratio are measured as shown in Fig. 8. At  $\frac{V_2}{V_1} = 1$ , near maximum efficiency (with less than 1% error) can be achieved under different loading conditions. Therefore,  $\frac{V_2}{V_1} = 1$  is used as the control reference for achieving maximum efficiency.

## B. Small-Signal Response

Fig. 9 shows the measured frequency response of the input duty cycle to the voltage error of the SSIPT converter. It matches the simulation result shown in Fig. 6(a) and verifies that the design of small-signal parameters of the controller for the cascaded buck-SSIPT converter can follow that of a buck converter.

# C. Transient Response Against Variation of k

To show the performance of the proposed control, variation of the air gap distance is introduced by using a DC motor which dynamically varies the position of the secondary-side coupler. In Fig. 7, an enlarged image shows the prototype of the loosely coupled transformer with position variation driven by a motor. At position A, the air gap distance g is 25 mm and the coupling coefficient k is 0.2541. At position B, g is 45 mm and the coupling coefficient k is 0.1217. More parameters of the loosely coupled transformer are shown in Table II.

Experimental waveforms using voltage error control for the dynamical variation of g at a time scale of 2 s/div are shown in Fig. 10. The efficiency of the system is kept at its optimum by observing that the instantaneous voltages  $V_2$  and  $V_1$  are kept almost identical under variation of k (or g).

As a comparison, experimental waveforms using an implementation of the minimum input current P&O control are also measured as shown in Fig. 11. The same variation speed of g as in Fig. 10 is used. In the minimum input current P&O control, a perturbation frequency 20 times faster than that adopted in [18] is used with the same perturbation size. Thus, the P&O control in this paper is theoretically faster than that in [18]. Fig. 11 shows that, the instantaneous input current  $I_{IN}$  needs more than 8 s to settle to the steady-state solution. The response of this P&O control is much slower than the voltage error control proposed in this paper against variations of k.

#### D. Transient Response Against Load Variations

Fig. 12 shows the waveforms of voltage tracking processes of the load R switching from 55 to 10  $\Omega$  and from 10  $\Omega$  back to 55  $\Omega$ . Using the PI controller, the steady-state error is eliminated. Within 300 ms, the input voltage  $V_1$  and the output voltage  $V_2$  are tracked, so that maximum efficiency of the system is

 $\frac{V_2}{V_2} = 0.8 - 1.2$ 

 $|\leq 1\%$ 

 $\mathbf{1}^{V_1}$ 

 $\begin{array}{c} \frac{V_2}{V_1}=0.8\\ \frac{V_2}{V_1}=0.9\\ \frac{V_2}{V_1}=1\\ \frac{V_2}{V_1}=1.1\\ \frac{V_2}{V_1}=1.2\\ \frac{V_2}{V_1}=0.5 \end{array}$ 

= 1.8

0

×

+

\*

 $\nabla$ 

70 80 90 100

Converter	Parameters	Symbol	Value			
Buck	Switch	$S_a$	IRF540N			
	Diode	$D_a$	MBR20100CTG			
	Inductor	$L_a$	1.2 mH			
	Capacitor	$C_a$	780 $\mu F$			
	Switches	$S_{b1}$ - $S_{b4}$	MTP5P06V			
	Diode	$D_{b1}$ - $D_{b4}$	MBR20100CTG			
	Inner diameter	$d_i$	9 mm			
	Coil width	w	1.2 mm			
	Outer diameter	$d_o$	88 mm			
	Primary turns	$N_P$	29			
	Secondary turns	$N_S$	30			
SSIPT	Air gap distance	g	45 mm	33 mm	25mm	
5511 1	Coupling coefficient	k	0.1217	0.1739	0.2541	
	Primary self inductance	$L_P$	$31.48 \ \mu H$	31.477 μH	31.467 μH	
	Secondary self inductance	$L_S$	$32.98 \ \mu H$	32.974 μH	32.955 μH	
	Primary winding resistance	$R_{P,w}$	245.8 m $\Omega$	245.76 mΩ	245.59 mΩ	
	Secondary winding resistance	$R_{S,w}$	246.3 m $\Omega$	246.32 mΩ	246.33 mΩ	
	Compensation capacitance	$C_P$	19.98 nF			
	Compensation capacitance	$C_S$	19.08 nF			
Buck-boost	Switch	$S_c$	IRF540N			
	Diode	$D_c$	MBR20100CTG			
	Capacitor	$C_{c1}$	680 $\mu$ F			
	Inductor	$L_c$	1.2 mH			
	Capacitor	$C_{c2}$	$470 \ \mu F$			





Fig. 8. Measured efficiency of the SSIPT converter versus output power under various voltage gains at (a) k = 0.1739, (b) k = 0.2541.



Fig. 9. Measurements of the frequency response of input duty cycle to voltage error of the SSIPT at (a) k = 0.1739, (b) k = 0.2541.

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Fig. 10. Transient waveforms of key control parameters of voltage error control with g dynamically changing (a) from 25 to 45 mm, and (b) from 45 mm back to 25 mm. The load resistance R is 10  $\Omega$ .



Fig. 11. Transient waveforms of key control parameters of an implementation of the minimum input current P&O control with g dynamically changing (a) from 25 to 45 mm, and (b) from 45 mm back to 25 mm. The loading condition is  $R = 10 \Omega$ .

maintained. We have performed experiments using the same parameters based on the P&O control implemented in Section V-C. We found that the transient voltage fluctuations can be harmful to the converters. Therefore, a reduced load range switching from 30 to 10  $\Omega$  is used for comparison of performance between the voltage error control and the P&O control. Four key parameters  $I_{\rm IN}$ ,  $V_1$ ,  $V_2$ , and  $V_{\rm OUT}$  of the system, as shown in Fig. 3, are chosen for the comparison of waveforms. In Fig. 13, the time base is set at 4 s/div, the test systems are open loop before  $t_1$  with  $R = 30 \Omega$ , the controls are applied after  $t_1$ , and the loads are switched to  $R = 10 \Omega$  at  $t_2$ .

Fig. 13(a) shows the transient waveforms when the voltage error control is used. It can be observed that  $V_{OUT}$  is always tightly regulated regardless of the excitations applied. This shows that the independently controlled load-side buck-boost converter can be stable with the input current  $I_2$  (not shown) and voltage  $V_2$  for the whole period of time indicated in Fig. 13(a). As soon as the voltage ratio control is applied at  $t_1$ ,  $V_2/V_1$  is immediately regulated at 1. At the same time,  $I_{IN}$  is also reduced immediately, thus improving the system efficiency. At  $t_2$ , the output power increases by threefold by switching the load

resistance from 30 to 10  $\Omega$ . The voltage ratio is rapidly followed and controlled with  $V_1 = V_2 = 30$  V at steady state.

Under the same experimental condition, the minimum input current P&O control produces the transient waveforms shown in Fig. 13(b). The system is completely out of control after  $t_2$ upon load switching. The system instability can be explained as follows. With the same initial condition as that of the voltage ratio control, the minimum input current P&O control is executed right after  $t_1$ . It takes more than 10 s to search for the minimum input current. As shown in Fig. 13(b), the voltage ratio  $V_2/V_1$  can be kept between 0.8 and 1.2, which are within the range of maximum efficiency as indicated in Fig. 8. At  $t_2$ , the output power increases three times by switching the load resistance from 30 to 10  $\Omega$ . The SSIPT converter is a transconductance converter and the load-side converter is a current-driven converter. The output current  $I_2$  of the SSIPT converter is proportional to  $V_1$ . Due to the slow regulation of  $V_1$  by the P&O control,  $I_2$  cannot keep up with the sudden large increment of the output power. However, the control loop of the load-side converter is fast. Therefore, the voltage input  $V_2$  of the current-driven load-side converter rises rapidly trying to acquire more power. As shown in Fig. 13(b),



Fig. 12. Transient waveforms of voltage tracking processes for R switching from 55 to 10  $\Omega$  and from 10 to 55  $\Omega$  at (a) k = 0.1739, (b) k = 0.2541.



Fig. 13. Transient waveforms of (a) voltage error control and (b) minimum input current P&O control. At  $t_1$ , the control is executed. At  $t_2$ , load resistance R is switched from 30 to 10  $\Omega$ . k is 0.1739.

TABLE III k-independent Converter Transfer Function at Maximum Efficiency

Topology	Converter at maximum efficiency
SS	$\frac{v_o}{v_i} = \sqrt{\frac{R_S}{R_P}}$
PS	$\frac{v_o}{i_i} = \omega L_S \sqrt{\frac{R_S}{R_P}}$

 $V_2$  becomes saturated because of over voltage, leading to the output voltage being out of control. By comparing Fig. 13(a) and (b), the voltage error control has better robustness against load variation due to its faster regulation speed.

# E. Discussion

For an IPT converter with a k-independent input-to-output transfer function and maximum efficiency, the linear control method proposed in this paper can be used. Two example converters are shown in Table III. The voltage input SS-topology is chosen as the example converter of the system. For IPT converters having k-dependent input-to-output transfer functions and maximum efficiency, before applying this linear control method, the k-dependent characteristic should be removed by some means, such as using a self-oscillating control as proposed in [26]. Design parameters of the IPT converters are usually known during the design phase. Equivalent series resistances  $R_P$  and  $R_S$  can be estimated from device parameters. The approximated voltage ratio  $V_2/V_1$  can be calculated using (6) as a control reference. Moreover, if the parameters are not available during the design phase or whenever verification is necessary, they can be measured experimentally as illustrated in Fig. 8. Alternatively, automatic in-circuit measuring methods, such as the P&O method, can also be implemented to determine the voltage ratio  $V_2/V_1$  at maximum efficiency dynamically at the expense of using more sensors. The voltage ratio  $V_2/V_1$  determined can be stored as a control reference for the linear control method proposed in this paper to improve performance.

# VI. CONCLUSION

To achieve maximum efficiency of an IPT system, it is common to use nonlinear P&O control for an IPT system consisting of an IPT converter cascaded with front-side and load-side dc/dc converters. The P&O control is inevitably slow. A linear control scheme is proposed to achieve fast MET for an IPT system in this paper. By observing that the maximum efficiency occurs at a specific input-to-output voltage transfer ratio, a small-signal model for the IPT converter and the front-side converter operating as a combined transconductance converter is developed in this paper. To be compatible with the current output of the transconductance converter, the load-side converter is designed with a standalone transresistance converter. The controllers for the system are analyzed and experimentally verified to be fast and effective in this paper.

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